

HCF4056B

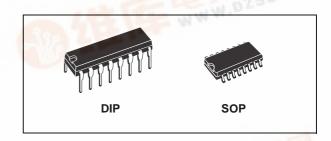
BCD TO 7 SEGMENT DECODER /DRIVER WITH STROBED LATCH FUNCTION

- QUIESCENT CURRENT SPECIF. UP TO 20V
- OPERATION OF LIQUID CRYSTALS WITH CMOS CIRCUITS PROVIDES ULTRA LOW POWER DISPLAY.
- EQUIVALENT AC OUTPUT DRIVE FOR LIQUID CRYSTAL DISPLAYS NO EXTERNAL CAPACITOR REQUIRED
- VOLTAGE DOUBLING ACROSS DISPLAY

 [(V_{DD} V_{EE}) = 18V] RESULTS IN EFFECTIVE
 36V (p-p) DRIVE ACROSS SELECTED
 DISPLAY SEGMENTS
- LOW OR HIGH OUTPUT LEVEL DC DRIVE FOR OTHER TYPES OF DISPLAYS
- ONE CHIP LOGIC LEVEL CONVERSION FOR DIFFERENT INPUT AND OUTPUT LEVEL SWINGS
- FULL DECODING OF ALL INPUT COMBINATIONS: "0 - 9, L, H, P, A" AND BLANK POSITIONS
- INPUT LEAKAGE CURRENT I_I = 100nA (MAX) AT V_{DD} = 18V T_A = 25°C
- 100% TESTED FOR QUIESCENT CURRENT
- MEETS ALL REQUIREMENTS OF JEDEC JESD13B "STANDARD SPECIFICATIONS FOR DESCRIPTION OF B SERIES CMOS DEVICES"

DESCRIPTION

HCF4056B is a monolithic integrated circuit fabricated in Metal Oxide Semiconductor technology available in DIP and SOP packages.

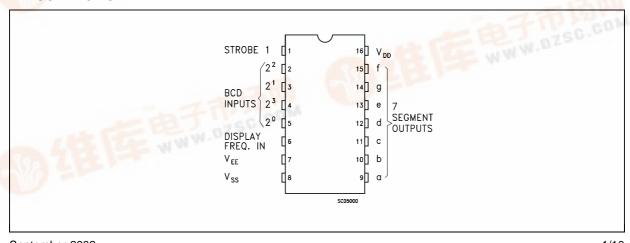


ORDER CODES

PACKAGE	TUBE	T & R
DIP	HCF4056BEY	M. Add
SOP	HCF4056BM1	HCF4056M013TR

HCF4056B is a single digit BCD to 7 segment decoder driver circuit that provides a level shifting function on the chip. This feature permits the BCD input-signal swings (V_{DD} to V_{SS}) to be the same as or different from the 7-segment output signal swings (V_{DD} to V_{EE}). For example, the BCD input-signal swings (V_{DD} to V_{SS}) may be as low as 0 to -3V, whereas the output-display drive signal swing (V_{DD} to V_{EE}) may be from 0 to -5V. If V_{DD} to V_{EE} exceeds 15V, V_{DD} to V_{SS} should be at least 4V. The 7-segment outputs are controlled by the DISPLAY-FREQUENCY (DF) input, which causes the selected segment outputs to be low, high, or a square wave output (for liquid crystal displays).

PIN CONNECTION

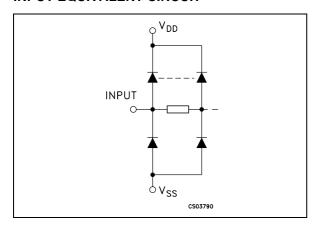


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When the DF input is low, the output segments will be high when selected by the BCD inputs. When the DF input is high, the output segments will be low when selected by the BCD inputs. When a square wave is present at the DF input, the selected segments will have a square wave output that is 180° out of phase with the DF input. Those segments which are not selected will have a square wave output that is in phase with the input. DF square wave repetition rates for liquid crystal displays usually range from 30Hz (well above flicker rate) to 200Hz (well below the upper limit of the liquid crystal frequency response). HCF4056B provides a strobed-latch function at the BCD inputs. The decoding of all input combinations in

this device provides displays of 0 to 9 as well as L, P, H, A, -, and a blank position. The level shifted function permits the use of different input and output signal swings. The input swings from a low level of V_{SS} to a high level of V_{DD} , while the outputs swing from a low level of V_{EE} to the same high level of V_{DD} . Thus, the input and output swings can be selected independently of each other over a 3 to 18V range. V_{SS} may be connected to V_{EE} when no level-shift function is required. The HCF4056B, however must be used together with HCF4054B to provide the common DF output.

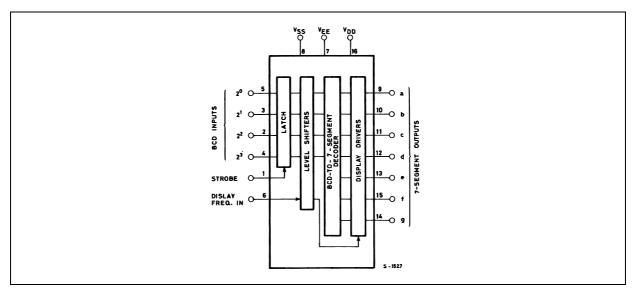
INPUT EQUIVALENT CIRCUIT



PIN DESCRIPTION

PIN No	SYMBOL	NAME AND FUNCTION
5, 3, 2, 4	$2^0, 2^1, 2^2, 2^3$	BCD Inputs
9, 10, 11, 12, 13, 15, 14	a to g	7 - Segments Outputs
6	DISPLAY FREQ. IN	Display Frequency Input
1	STROBE	Strobe Input
7	V_{EE}	Negative Supply Voltage
8	V _{SS}	Negative Supply Voltage
16	V_{DD}	Positive Supply Voltage

FUNCTIONAL DIAGRAM



TRUTH TABLE

	INPUT	CODE			DISPLAY						
2 ³	2 ²	2 ¹	2 ⁰	а	b	С	d	е	f	g	CHARACTER
L	L	L	L	Н	Н	Н	Н	Н	Н	L	0
L	L	L	Н	L	Н	Н	L	L	L	L	1
L	L	Н	L	Н	Н	L	Н	Н	L	Н	2
L	L	Н	Н	Н	Н	Н	Н	L	L	Н	3
L	Н	L	L	L	Н	Н	L	L	Н	Н	4
L	Н	L	Н	Н	L	Н	Н	L	Н	Н	5
L	Н	Н	L	Н	L	Н	Н	Н	Н	Н	6
L	Н	Н	Н	Н	Н	Н	L	L	L	L	7
Н	L	L	L	Н	Н	Н	Н	Н	Н	Н	8
Н	L	L	Н	Н	Н	Н	Н	L	Н	Н	9
Н	L	Н	L	L	L	L	Н	Н	Н	L	L
Н	L	Н	Н	L	Н	Н	L	Н	Н	Н	Н
Н	Н	Ĺ	L	Н	Η	L	L	Н	Н	Н	Р
Н	Н	Ĺ	Н	Н	Н	Н	L	Н	Н	Н	Α
Н	Н	Н	L	L	L	L	L	L	L	Н	-
Н	Н	Н	Н	L	L	L	L	L	L	L	BLANK

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{DD}	Supply Voltage	-0.5 to +22	V
VI	DC Input Voltage	-0.5 to V _{DD} + 0.5	V
I _I	DC Input Current	± 10	mA
P _D	Power Dissipation per Package	200	mW
	Power Dissipation per Output Transistor	100	mW
T _{op}	Operating Temperature	-55 to +125	°C
T _{stg}	Storage Temperature	-65 to +150	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

All voltage values are referred to V_{SS} pin voltage.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V_{DD}	Supply Voltage	3 to 20	V
V _I	Input Voltage	0 to V _{DD}	V
T _{op}	Operating Temperature	-55 to 125	°C



HCF4056B

DC SPECIFICATIONS

			Tes	st Condition	on					Value				
Symbol	Parameter	V _{EE}	Vı	v _o	v _{ss}	V _{DD}	T,	T _A = 25°C			85°C	-55 to 125°C		Unit
V _{OH}		(V)	(V)	(V)	(V)	(V)	Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
ΙL	Quiescent Current	-5	0/5		0	5		0.04	5		150		150	
		0	0/10		0	10		0.04	10		300		300	μΑ
		0	0/15		0	15		0.04	20		600		600	μΛ
		0	0/20		0	20		0.08	100		3000		3000	
V _{OH}	High Level Output	0	0/5		0	5	4.95			4.95		4.95		
	Voltage	0	0/10		0	10	9.95			9.95		9.95		V
		0	0/15		0	15	14.95			14.95		14.95		
V _{OL}	Low Level Output	0	5/0		0	5		0.05			0.05		0.05	
	Voltage	0	10/0		0	10		0.05			0.05		0.05	
		0	15/0		0	15		0.05			0.05		0.05	
V_{IH}	High Level Input	-5		0.5/4.5	0	5	3.5			3.5		3.5		
	Voltage	0		1/9	0	10	7			7		7		V
		0		1.5/18.5	0	15	11			11		11		
V_{IL}	Low Level Input	5		0.5/4.5	0	5			1.5		1.5		1.5	
	Voltage	0		9/1	0	10			3		3		3	V
		0		1.5/18.5	0	15			4		4		4	
I _{OH}	Output Drive	-5	0/5	4.5	0	5	-0.38	-0.9		-0.28		-0.28		
	Current	0	0/10	9.5	0	10	-0.38	-0.9		-0.28		-0.28		mΑ
		0	0/15	13.5	0	15	-1.27	-3		-0.95		-0.95		
I _{OL}	Output Sink	-5	0/5	0.4	0	5	1.1	2.6		0.82		0.82		
	Current	0	0/10	0.5	0	10	1.1	2.6		0.82		0.82		mΑ
		0	0/15	1.5	0	15	2.9	6.8		2.17		2.17		
lı	Input Leakage Current (any input)	0	0/18		0	18		±10 ⁻⁵	±0.1		±1		±1	μΑ
C _I	Input Capacitance (any input)							5	7.5	oin with	\/ 15			pF

The Noise Margin for both "1" and "0" level is: 1V min. with V_{DD} =5V, 2V min. with V_{DD} =10V, 2.5V min. with V_{DD} =15V

$\textbf{DYNAMIC ELECTRICAL CHARACTERISTICS} \; (T_{amb} = 25^{\circ}C, \;\; C_{L} = 50 pF, \; R_{L} = 200 \text{K}\Omega, \;\; t_{f} = t_{f} = 20 \; \text{ns})$

		Test Condition				Value (*)			Unit
Symbol	Parameter	V _{EE} (V)	V _{SS} (V)	V _{DD} (V)		Min.	Тур.	Max.	
t _{PHL} t _{PLH}	Propagation Delay	-5	0	5			650	1300	
	Time (any Input to any Output)	0	0	10			575	1150	ns
		0	0	15			375	750	
t _{THL} t _{TLH}	Transition Time (any Output)	-5	0	5			100	200	
		0	0	10			100	200	ns
		0	0	15		•	75	150	

(*) Typical temperature coefficient for all V_{DD} value is 0.3 %/°C.

TYPICAL APPLICATIONS

FIGURE 1: Display Driver Circuit

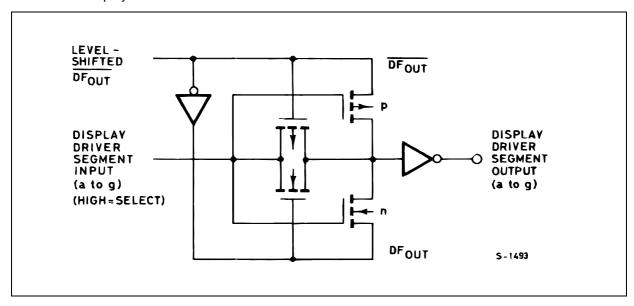


FIGURE 2: Display Driver Waveforms.

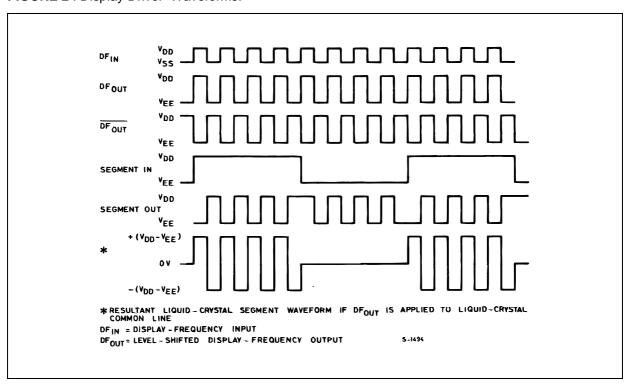
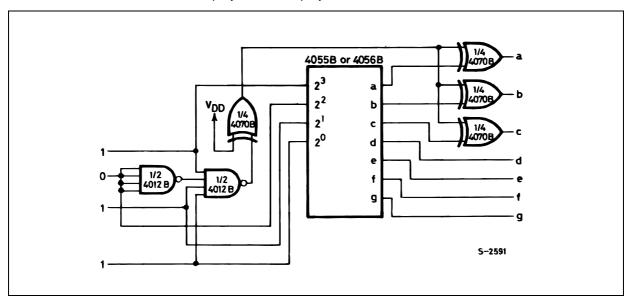
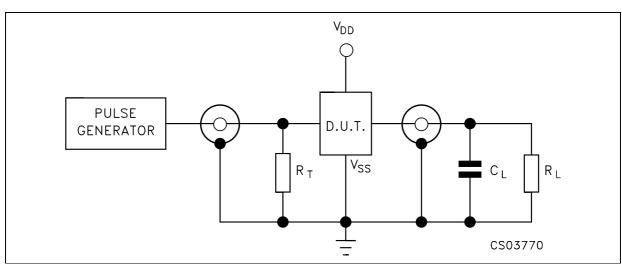


FIGURE 3 : Conversion Of "H" Display To "F" Display



Example of a circuit that converts an "H" display (code 1011) to an "F" display.

TEST CIRCUIT

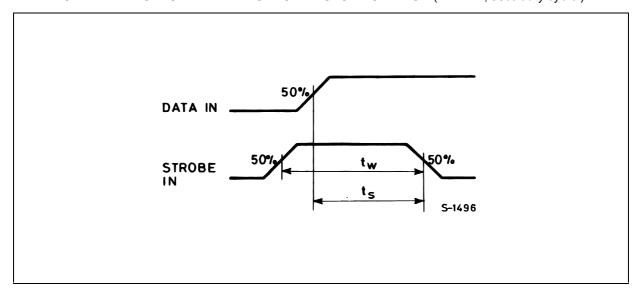


 $C_L = 50 pF$ or equivalent (includes jig and probe capacitance)

 $R_L = 200 K\Omega$

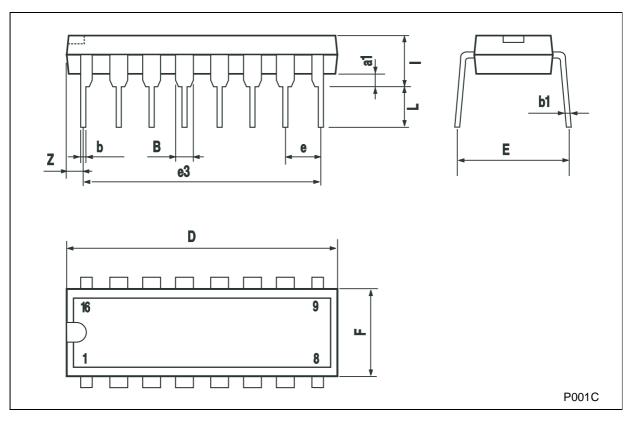
 $R_T = Z_{OUT}$ of pulse generator (typically 50 Ω)

WAVEFORM: DATA SETUP TIME AND STROBE PULSE DURATION (f=1MHz; 50% duty cycle)



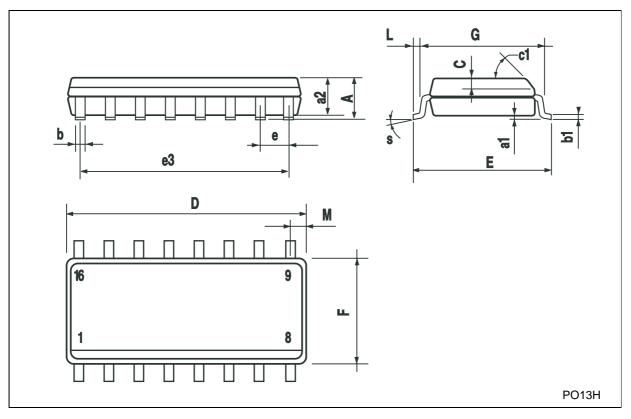
Plastic DIP-16 (0.25) MECHANICAL DATA

DIM.		mm.		inch					
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.			
a1	0.51			0.020					
В	0.77		1.65	0.030		0.065			
b		0.5			0.020				
b1		0.25			0.010				
D			20			0.787			
E		8.5			0.335				
е		2.54			0.100				
e3		17.78			0.700				
F			7.1			0.280			
I			5.1			0.201			
L		3.3			0.130				
Z			1.27			0.050			



SO-16 MECHANICAL DATA

DIM		mm.		inch					
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.			
Α			1.75			0.068			
a1	0.1		0.2	0.003		0.007			
a2			1.65			0.064			
b	0.35		0.46	0.013		0.018			
b1	0.19		0.25	0.007		0.010			
С		0.5			0.019				
c1			45°	(typ.)					
D	9.8		10	0.385		0.393			
E	5.8		6.2	0.228		0.244			
е		1.27			0.050				
e3		8.89			0.350				
F	3.8		4.0	0.149		0.157			
G	4.6		5.3	0.181		0.208			
L	0.5		1.27	0.019		0.050			
М			0.62			0.024			
S			ຄໍ (r	max.)					



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